

APT15D100BHB 1000V 2x15A

ULTRAFast SOFT RECOVERY RECTIFIER DIODES

PRODUCT APPLICATIONS	PRODUCT FEATURES	PRODUCT BENEFITS
<ul style="list-style-type: none"> • Output Rectifiers for Switchmode Power Supply 	<ul style="list-style-type: none"> • Ultrafast Recovery Times • Soft Recovery Characteristics • Popular TO-247 Package • Low Forward Voltage • High Blocking Voltage • Low Leakage Current 	<ul style="list-style-type: none"> • Low Losses • Low Noise Switching • Cooler Operation • Higher Reliability Systems • Increased System Power Density

MAXIMUM RATINGS All Ratings Are Per Leg: $T_C = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Characteristic / Test Conditions	APT15D100BHB	UNIT
V_R	Maximum D.C. Reverse Voltage	1000	Volts
V_{RRM}	Maximum Peak Repetitive Reverse Voltage		
V_{RWM}	Maximum Working Peak Reverse Voltage		
$I_F(AV)$	Maximum Average Forward Current ($T_C = 90^\circ\text{C}$, Duty Cycle = 0.5)	15	Amps
$I_F(RMS)$	RMS Forward Current	25	
I_{FSM}	Non-Repetitive Forward Surge Current ($T_J = 45^\circ\text{C}$, 8.3ms)	80	
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
T_L	Lead Temperature: 0.063" from Case for 10 Sec.	300	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
V_F	Maximum Forward Voltage			2.3	Volts
				$I_F = 15\text{A}$	
				$I_F = 30\text{A}$	
I_{RM}	Maximum Reverse Leakage Current			1.9	μA
				$V_R = V_R \text{ Rated}$	
				$V_R = V_R \text{ Rated}, T_J = 125^\circ\text{C}$	
C_T	Junction Capacitance, $V_R = 200\text{V}$		12		pF
L_S	Series Inductance (Lead to Lead 5mm from Base)		10		nH

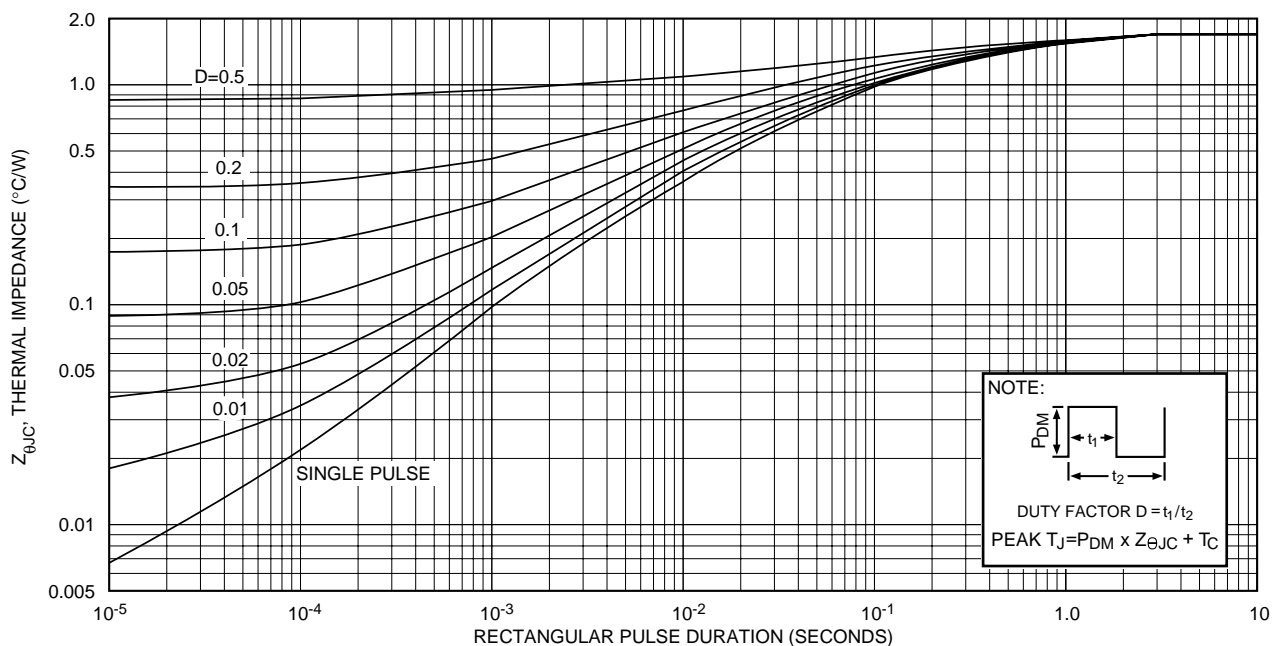
DYNAMIC CHARACTERISTICS

APT15D100BHB

Symbol	Characteristic	MIN	TYP	MAX	UNIT
t_{rr1}	Reverse Recovery Time, $I_F = 1.0A$, $di_F/dt = -15A/\mu s$, $V_R = 30V$, $T_J = 25^\circ C$		60	75	ns
t_{rr2}	Reverse Recovery Time		60		
t_{rr3}	$I_F = 15A$, $di_F/dt = -100A/\mu s$, $V_R = 540V$		120		
t_{fr1}	Forward Recovery Time		180		
t_{fr2}	$I_F = 15A$, $di_F/dt = 100A/\mu s$, $V_R = 540V$		180		
I_{RRM1}	Reverse Recovery Current		3.8	7	Amps
I_{RRM2}	$I_F = 15A$, $di_F/dt = -100A/\mu s$, $V_R = 540V$		4.5	9	
Q_{rr1}	Recovery Charge		114		nC
Q_{rr2}	$I_F = 15A$, $di_F/dt = -100A/\mu s$, $V_R = 540V$		270		
V_{fr1}	Forward Recovery Voltage		5.8		Volts
V_{fr2}	$I_F = 15A$, $di_F/dt = 100A/\mu s$, $V_R = 540V$		5.8		
diM/dt	Rate of Fall of Recovery Current		100		A/ μs
	$I_F = 15A$, $di_F/dt = -100A/\mu s$, $V_R = 540V$ (See Figure 10)		50		

THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			1.7	$^\circ C/W$
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance			80	
W_T	Package Weight		0.07		oz
			1.9		gm
Torque	Maximum Mounting Torque (Screw Type = 6-32 or 3.5mm Machine)			6.4	lb•in
				0.7	N•m



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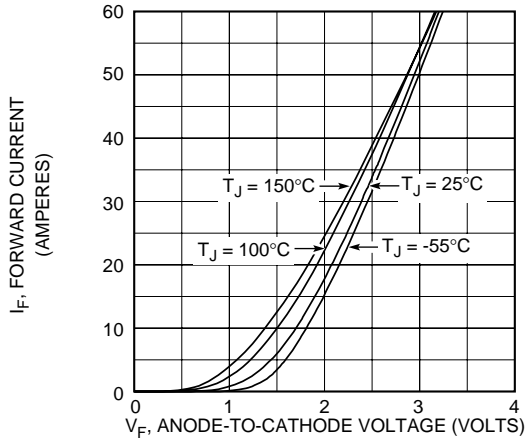


Figure 2, Forward Voltage Drop vs Forward Current

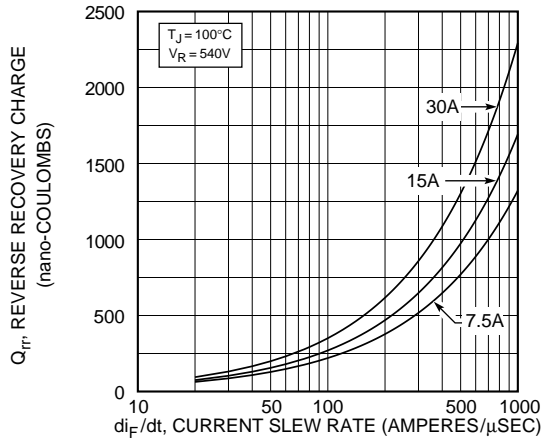


Figure 3, Reverse Recovery Charge vs Current Slew Rate

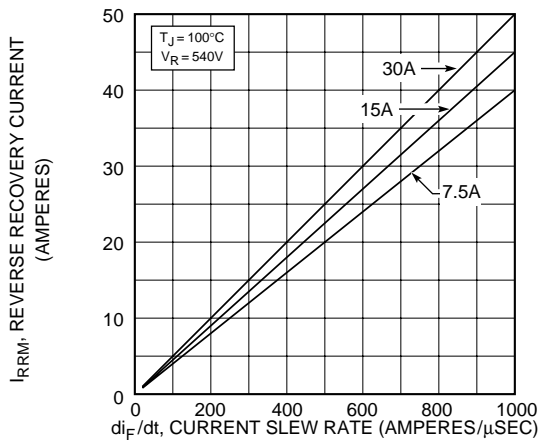


Figure 4, Reverse Recovery Current vs Current Slew Rate

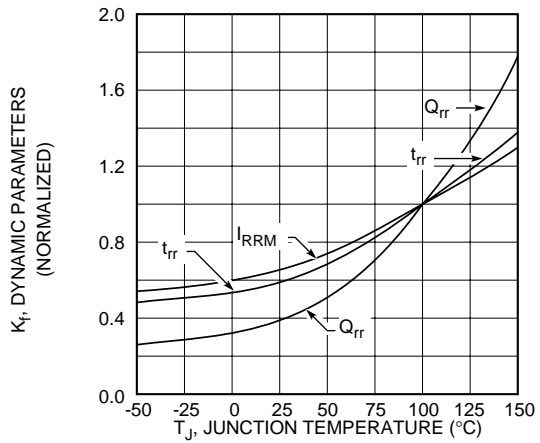


Figure 5, Dynamic Parameters vs Junction Temperature

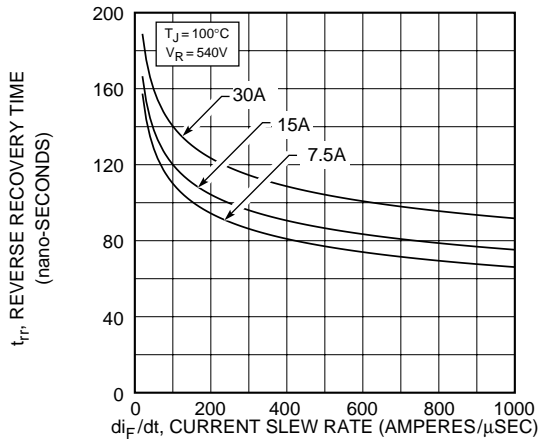


Figure 6, Reverse Recovery Time vs Current Slew Rate

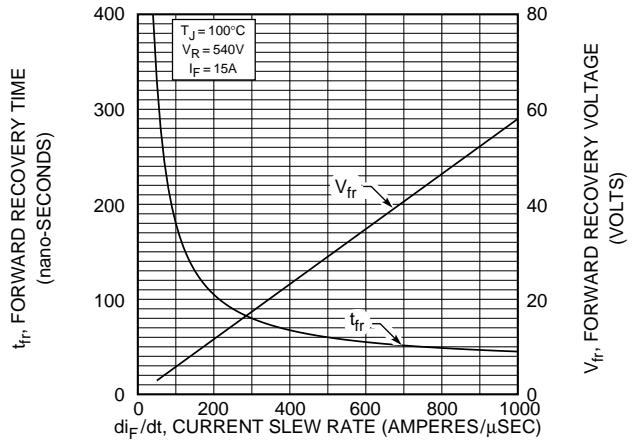


Figure 7, Forward Recovery Voltage/Time vs Current Slew Rate

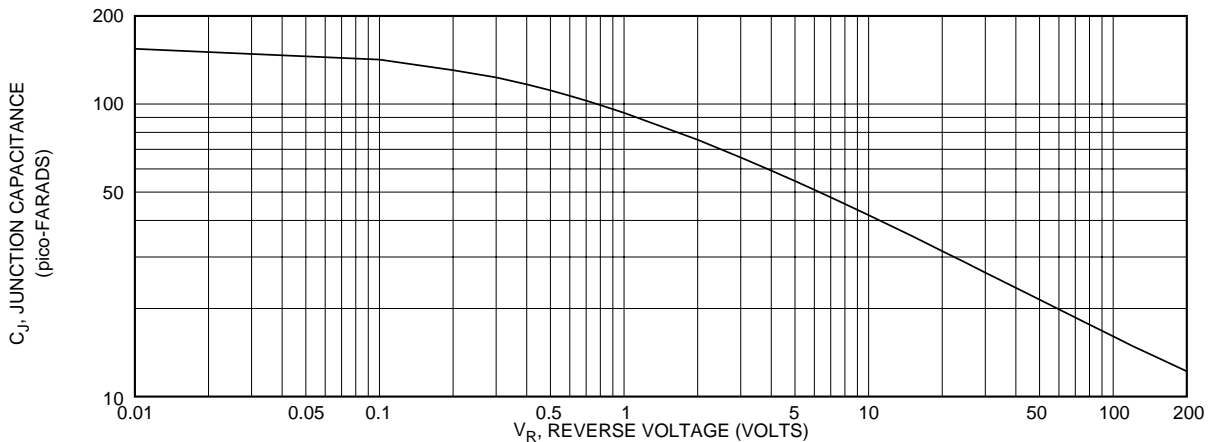


Figure 8, Junction Capacitance vs Reverse Voltage

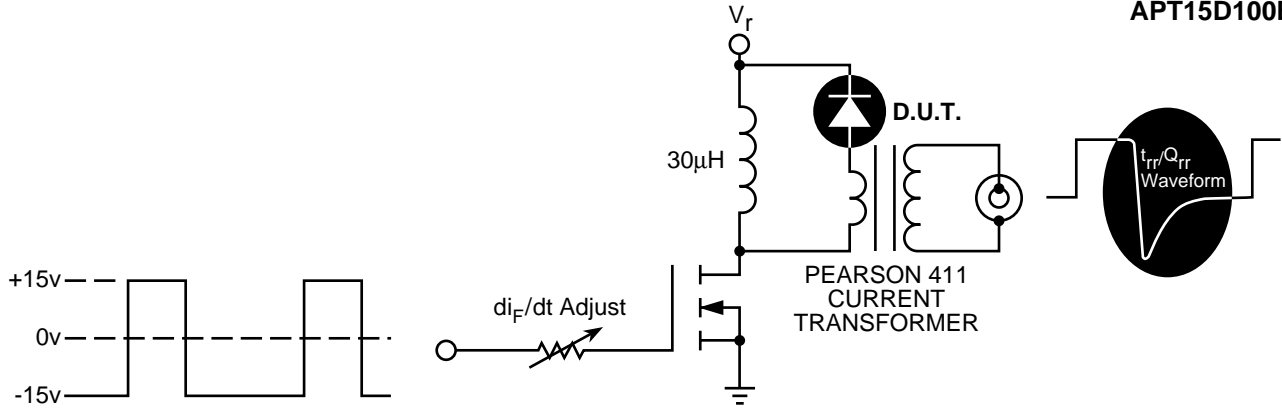


Figure 9, Diode Reverse Recovery Test Circuit and Waveforms

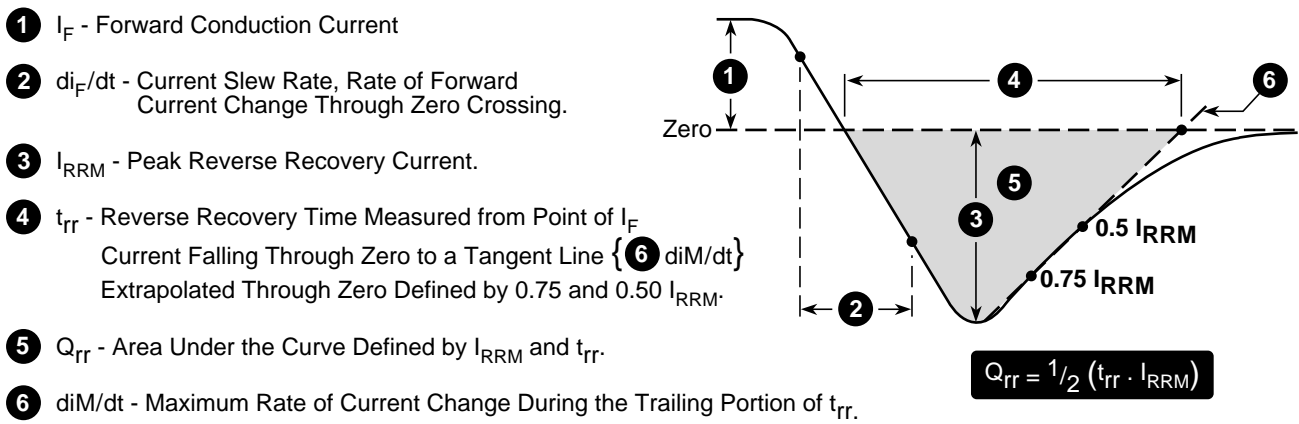
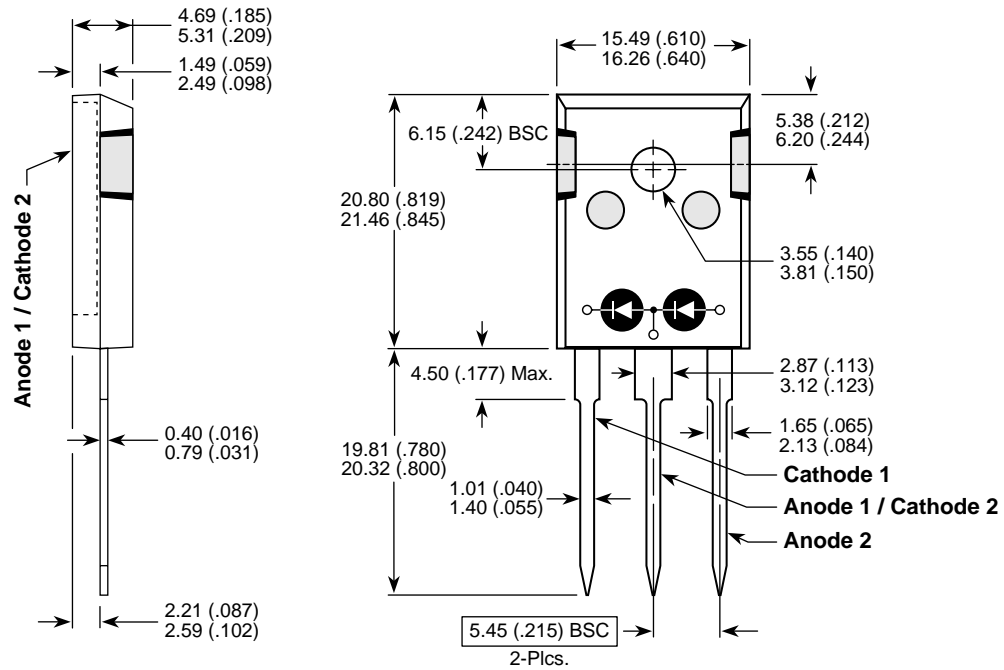


Figure 10, Diode Reverse Recovery Waveform and Definitions

TO-247 Package Outline



Dimensions in Millimeters and (Inches)